

## Trans IGBT Chip N-CH 1800V 40A 375mW 3-Pin(3+Tab) TO-3PN



Images are for reference only

[Inquiry](#)

**Manufacturer:** [Toshiba Semiconductor](#)

**Package/Case:** TO-3P

**Product Type:** Thyristors

**RoHS:** RoHS Compliant/Lead free 

**Lifecycle:** Active

### General Description

Feature:Fast switching / Low saturation voltage  
 Number of Circuits:2  
 Built-in Diodes:Yes  
 RoHS Compatible Product(s) (#):Available  
 Assembly bases:Japan

### Recommended For You

#### GT30J121

Toshiba Semiconductor  
TO-3P

#### GT20J301

Toshiba Semiconductor  
TO-3P

#### GT40QR21

Toshiba Semiconductor  
TO-3P

#### GT20J341

Toshiba Semiconductor  
TO-220SIS

#### GT50J102

Toshiba Semiconductor  
TO-3PL

#### GT30J322(Q)

Toshiba Semiconductor  
BGA

#### GT15J341

Toshiba Semiconductor  
TO-220F

#### GT30J341

Toshiba Semiconductor  
TO-247

#### GT40RR21

Toshiba Semiconductor  
TO-3P

#### GT50N322A

Toshiba Semiconductor  
TO-3P(N)

#### GT60MB23

Toshiba Semiconductor  
TO-3PL

#### GT40WR21,Q

Toshiba Semiconductor  
SMT

**GT50JR21(STA1,E,S)**

Toshiba Semiconductor

SMT

**GT10GI31(TE12L,Q)**

Toshiba Semiconductor

337-NFBGA16x16

**GT8GI33(TE12L,Q)**

Toshiba Semiconductor

BGA